BLP10H610

Broadband LDMOS driver transistor

AMPLEON Product data sheet

Rev. 4 — 1 September 2015

1. Product profile

1.1 General description

A 10 W plastic LDMOS power transistor for broadcast transmitter and ISM applications at frequencies from HF to 1400 MHz.

Table 1. Application performance

Test signal	f	V _{DS}	PL	Gp	η _D
	(MHz)	(V)	(W)	(dB)	(%)
CW	27	50	10	26.7	46
	40	50	20	25	65
	60	50	19	24	65
	80	50	19	25	67
	88 to 108	50	16	25	62
	400 to 450	50	>14	>25.5	>62
	950 to 1225	50	>13	>16	>42
Pulsed RF [1]	860	50	10	22	60
	1190 to 1410	45	11	>14	-
DVB-T	860	50	1	>21	-

^[1] $t_p = 100 \,\mu\text{s}; \, \delta = 10 \,\%.$

1.2 Features and benefits

- Easy power control
- Integrated ESD protection
- Excellent ruggedness
- High efficiency
- Excellent thermal stability
- Designed for broadband operation (HF to 1400 MHz)
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- Industrial, scientific and medical applications
- Broadcast transmitter applications

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2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1, 6, 7, 12	n.c.		40.44
2, 3	gate1	1 12	10, 11
4, 5	gate2	2 11 3 10	
8, 9	drain2	4 9	2, 3—1—13
10, 11	drain1	5	4, 5
13	source [° L L J '	" <u>¬</u>
		Transparent top view	8, 9 aaa-010491

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package	Package				
	Name	Description	Version			
BLP10H610	HVSON12	plastic thermal enhanced very thin small outline package; no leads; 12 terminals; body $5\times6\times0.85$ mm	SOT1352-1			

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	104	V
V_{GS}	gate-source voltage		-6	+11	V
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C

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5. Recommended operating conditions

See application note AN11520 for more details.

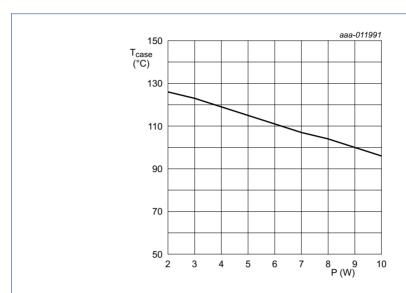


Fig 1. Recommended operating area; case temperature as a function of power dissipation

6. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Тур	Unit
R _{th(j-c)}	thermal resistance from junction to case	$T_{case} = 80 ^{\circ}C; P_{L} = 10 W$ [1]	3.5	K/W

^[1] $R_{th(j-c)}$ is measured under RF conditions

7. Characteristics

Table 6. DC characteristics

 $T_j = 25$ °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_D = 0.12 \text{ mA}$	104	-	-	V
V _{GS(th)}	gate-source threshold voltage	V _{DS} = 10 V; I _D = 12 mA	1.25	1.75	2.25	V
V_{GSq}	gate-source quiescent voltage	$V_{DS} = 50 \text{ V}; I_D = 60 \text{ mA}$	1.4	1.8	2.15	V
I _{DSS}	drain leakage current	V _{GS} = 0 V; V _{DS} = 50 V	-	-	1.4	μΑ
I _{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$	-	1.88	-	А
I _{GSS}	gate leakage current	$V_{GS} = 11 \text{ V}; V_{DS} = 0 \text{ V}$	-	-	140	nA
R _{DS(on)}	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $I_D = 420 \text{ mA}$	-	2300	-	mΩ

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Table 7. AC characteristics

 $T_i = 25$ °C; unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C _{rs}	feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	0.13	-	pF
C _{iss}	input capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 0 \text{ V}; f = 1 \text{ MHz}$	-	13.5	-	pF
Coss	output capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 50 \text{ V}; f = 1 \text{ MHz}$	-	4.5	-	pF

Table 8. RF characteristics

Test signal: CW; f = 860 MHz; RF performance at $V_{DS} = 50$ V; $I_{Dq} = 60$ mA; $T_{case} = 25$ °C; unless otherwise specified, in a class-AB production test circuit 11.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Gp	power gain	P _L = 10 W	19.3	22	25.7	dB
η_{D}	drain efficiency	P _L = 10 W	56.8	60	-	%

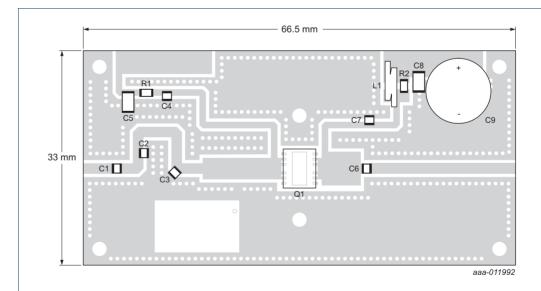
^[1] The industrial test method is performed on special hardware to accommodate the requirements of production. The test results in this table are correlated to correspond with a performance in the application.

8. Test information

8.1 Ruggedness in class-AB operation

The BLP10H610 is capable of withstanding a load mismatch corresponding to VSWR = 35 : 1 through all phases under the following conditions: V_{DS} = 50 V; I_{Dq} = 60 mA; P_L = 10 W; f = 860 MHz.

8.2 Test circuit



Printed-Circuit Board (PCB): Rogers RO4350; ϵ_{r} = 3.48; height = 0.762 mm; thickness copper plating = 35 μ m.

See Table 9 for a list of components.

Fig 2. Component layout

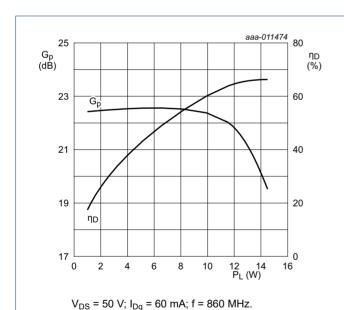
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Table 9. **List of components** See Figure 2 for component layout.

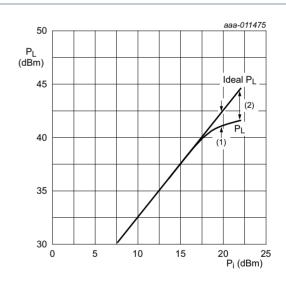
Component	Description	Value	Remarks
C1, C4, C7	multilayer ceramic chip capacitor	100 pF [1]	
C2	multilayer ceramic chip capacitor	5.6 pF [1]	
C3	multilayer ceramic chip capacitor	3.9 pF [1]	
C5	multilayer ceramic chip capacitor	1 μF, 25 V	Murata GRM31MR71E105KA01L
C6	multilayer ceramic chip capacitor	4.3 pF [1]	
C8	multilayer ceramic chip capacitor	1 μF, 50 V	Murata GRM32RR71H105KA01L
C9	electrolytic capacitor	220 μF, 63 V	
L1	wire inductor, 0.8 mm copper wire	2 turn, D = 3 mm	
R1	resistor	0 Ω	SMD 0805
R2	resistor	20 Ω	SMD 0805
Q1	transistor	-	BLP10H610

^[1] American Technical Ceramics type 100A or capacitor of same quality.

8.3 Graphical data



Power gain and drain efficiency as function of Fig 3. output power; typical values

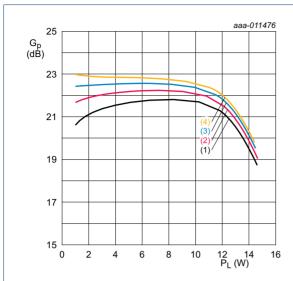


 V_{DS} = 50 V; I_{Dq} = 60 mA; f = 860 MHz.

- (1) $P_{L(1dB)} = 40.93 \text{ dBm } (12.4 \text{ W})$
- (2) $P_{L(3dB)} = 41.61 \text{ dBm } (14.5 \text{ W})$

Fig 4. Output power as a function of input power; typical values

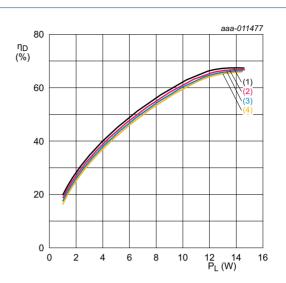
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V_{DS} = 50 V; f = 860 MHz.

- (1) $I_{Dq} = 20 \text{ mA}$
- (2) $I_{Dq} = 40 \text{ mA}$
- (3) $I_{Dq} = 60 \text{ mA}$
- (4) $I_{Dq} = 80 \text{ mA}$

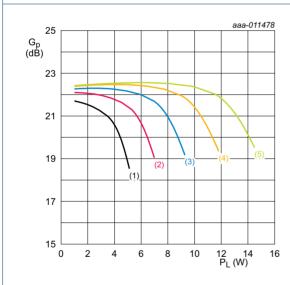
Fig 5. Power gain as a function of output power; typical values



 $V_{DS} = 50 \text{ V}; f = 860 \text{ MHz}.$

- (1) $I_{Dq} = 20 \text{ mA}$
- (2) $I_{Dq} = 40 \text{ mA}$
- (3) $I_{Dq} = 60 \text{ mA}$
- (4) $I_{Dq} = 80 \text{ mA}$

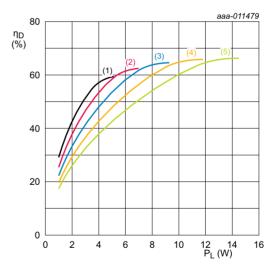
Fig 6. Drain efficiency as a function of output power; typical values



 $I_{Dq} = 60 \text{ mA}$; f = 860 MHz.

- (1) $V_{DS} = 30 \text{ V}$
- (2) $V_{DS} = 35 V$
- (3) $V_{DS} = 40 \text{ V}$
- (4) $V_{DS} = 45 \text{ V}$
- (5) $V_{DS} = 50 \text{ V}$

Fig 7. Power gain as a function of output power; typical values



 $I_{Dq} = 60 \text{ mA}$; f = 860 MHz.

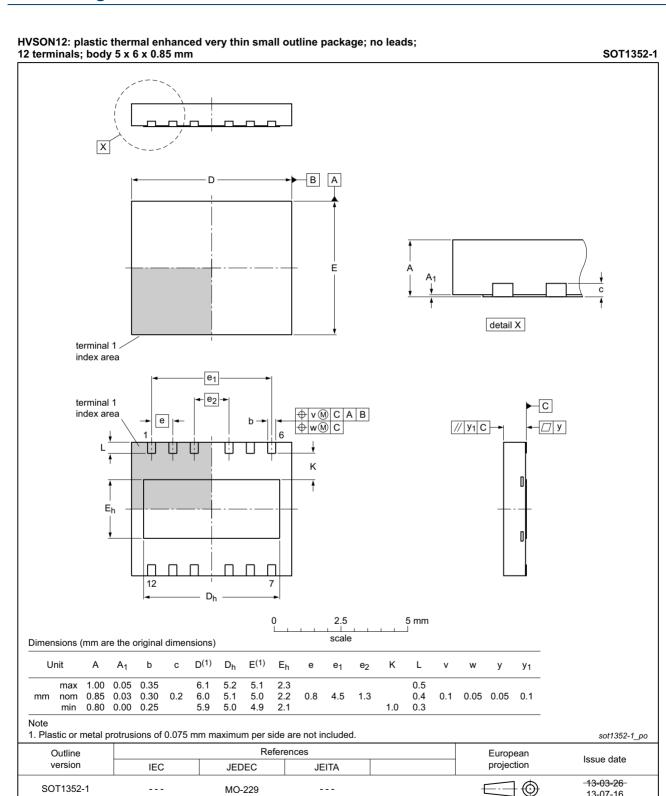
- (1) $V_{DS} = 30 \text{ V}$
- (2) $V_{DS} = 35 V$
- (3) $V_{DS} = 40 \text{ V}$
- (4) $V_{DS} = 45 \text{ V}$
- (5) $V_{DS} = 50 \text{ V}$

Fig 8. Drain efficiency as a function of output power; typical values

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Package outline



Package outline SOT1352-1 (HVSON12) Fig 9.

13-07-16

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10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

11. Abbreviations

Table 10. Abbreviations

Acronym	Description	
CW	Continuous Wave	
DVB-T	Digital Video Broadcast - Terrestrial	
ESD	ElectroStatic Discharge	
LDMOS	Laterally Diffused Metal-Oxide Semiconductor	
HF	High Frequency	
ISM	Industrial, Scientific and Medical	
SMD	Surface Mounted Device	
VSWR	Voltage Standing-Wave Ratio	

12. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes	
BLP10H610#4	20150901	Product data sheet		BLP10H610 v.3	
Modifications:	of Ampleon.	 The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. Legal texts have been adapted to the new company name where appropriate. 			
BLP10H610 v.3	20140925	Product data sheet	-	BLP10H610 v.2	
BLP10H610 v.2	20140422	Objective data sheet	-	BLP10H610 v.1	
BLP10H610 v.1	20140120	Objective data sheet	-	-	

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13.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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